

Application Data Sheet

Application Information

Application Type::	Regular
Subject Matter::	Utility
Suggested Group Art Unit::	Not Yet Assigned
CD-ROM or CD-R?::	None
Sequence submission?::	None
Computer Readable Form (CRF)?::	No
Title::	SEMICONDUCTOR MEMORY DEVICE AND METHOD FOR PROGRAMMING AND ERASING A MEMORY CELL
Attorney Docket Number::	559502000500
Request for Early Publication?::	No
Request for Non-Publication?::	No
Total Drawing Sheets::	15
Small Entity?::	No
Petition included?::	No
Secrecy Order in Parent Appl.?::	No

Applicant Information

Applicant Authority Type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given Name::	Nobuaki
Family Name::	MATSUOKA
City of Residence::	Tenri
Country of Residence::	Japan
Street of mailing address::	Rapport Tenri #446, 2613-1 Ichinomoto-cho
City of mailing address::	Tenri
State or Province of mailing address::	Nara
Country of mailing address::	Japan

Postal or Zip Code of mailing address:: 632-0004

Correspondence Information

Correspondence Customer Number:: 25226

Representative Information

Representative Customer Number:: 25226

Foreign Priority Information

Country::	Application number::	FilingDate::	Priority Claimed::
Japan	2002-353053	12/04/02	Yes
Japan	2003-018645	01/28/03	Yes

Assignee Information

Assignee name:: SHARP KABUSHIKI KAISHA
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